

PART NUMBER	COMPONENT DENSITY	SPEED	MT/S	I/O VOLTAGE	OPERATING TEMP	BUS WIDTH	CAS LATENCY	PIN COUNT	PART STATUS CODE	COMPONENT CONFIG	PACKAGE	FAMILY	TECHNOLOGY	NUMBER OF COMPONENTS	DRY PACK QTY	PART TYPE	PLP	TAPE & REEL QTY
MT41K64M16TW-107 AAT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x16	CL = 13	96-ball	Production	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41J128M16JT-125:K	2Gb	800MHz	1600MTPS	1.5 VOLTS	0C to +95C	x16	CL = 11	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K256M16TW-107:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K256M16TW-107 AAT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K64M16TW-107 XIT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41K256M16TW-107 AIT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K128M16JT-125 XIT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 11	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41K256M16V00HWC1	4Gb			1.5 VOLTS	0C to +95C	x16			Contact Factory	256M x16		DRAM	DDR3 SDRAM	1		DIE		
MT41K256M16TW-107 XIT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41K256M8DA-125:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	0C to +95C	x8	CL = 11	78-ball	Production	256M x8	FBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K512M16VRP-107 AIT:P	8Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Contact Factory	512M x16	TFBGA	DRAM	DDR3 SDRAM	2	1224 COMPONENT			2000
MT41K256M8DA-107:K	2Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x8	CL = 13	78-ball	Production	256M x8	FBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K256M16TW-107 IT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K64M16TW-107:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x16	CL = 13	96-ball	Production	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K512M8DA-093:P	4Gb	1066MHz	2133MTPS	1.35 VOLTS	0C to +95C	x8	CL = 14	78-ball	Production	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K512M8DA-107 IT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 13	78-ball	Production	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K128M8DA-107 IT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 13	78-ball	Production	128M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K64M16TW-107 IT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K512M8DA-107:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x8	CL = 13	78-ball	Production	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K512M16VRP-107 IT:P	8Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	512M x16	TFBGA	DRAM	DDR3 SDRAM	2	1224 COMPONENT			2000
MT41K128M16JT-125:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	0C to +95C	x16	CL = 11	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K128M16JT-107 IT:K	2Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K256M8DA-125 AIT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 11	78-ball	Production	256M x8	FBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT	YES		2000
MT41K256M8DA-107 AAT:K	2Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x8	CL = 13	78-ball	Contact Factory	256M x8	FBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K512M8DA-107 AAT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x8	CL = 13	78-ball	Contact Factory	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K512M8DA-107 XIT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 13	78-ball	End of Life	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT	YES		2000
MT41K128M16JT-125 AUT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +125C	x16	CL = 11	96-ball	Production	128M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K512M8DA-107 AIT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 13	78-ball	End of Life	512M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K256M16TW-107 AUT:P	4Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +125C	x16	CL = 13	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K1G8RKB-107:P	8Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x8	CL = 13	78-ball	Production	1G x8	TFBGA	DRAM	DDR3 SDRAM	2	1440 COMPONENT			2000
MT41J128M16JT-093:K	2Gb	1066MHz	2133MTPS	1.5 VOLTS	0C to +95C	x16	CL = 14	96-ball	Contact Factory	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K512M16VRP-107 AAT:P	8Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x16	CL = 13	96-ball	Production	512M x16	TFBGA	DRAM	DDR3 SDRAM	2	1224 COMPONENT			2000
MT41K256M8DA-125 IT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +95C	x8	CL = 11	78-ball	Production	256M x8	FBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			2000
MT41K256M16TW-093:P	4Gb	1066MHz	2133MTPS	1.35 VOLTS	0C to +95C	x16	CL = 14	96-ball	Production	256M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K64M16TW-107 AUT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +125C	x16	CL = 13	96-ball	Contact Factory	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K128M16JT-107 AAT:K	2Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +105C	x16	CL = 13	96-ball	Production	128M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K64M16TW-107 AIT:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 13	96-ball	Production	64M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41K128M16JT-125 AIT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 11	96-ball	Production	128M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000
MT41K128M8DA-107:J	1Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x8	CL = 13	78-ball	Production	128M x8	TFBGA	DRAM	DDR3 SDRAM	1	1440 COMPONENT			1000
MT41K128M16JT-107:K	2Gb	933MHz	1866MTPS	1.35 VOLTS	0C to +95C	x16	CL = 13	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K128M16JT-125 IT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +95C	x16	CL = 11	96-ball	Production	128M x16	FBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT			2000
MT41K128M16JT-125 AAT:K	2Gb	800MHz	1600MTPS	1.35 VOLTS	-40C to +105C	x16	CL = 11	96-ball	Production	128M x16	TFBGA	DRAM	DDR3 SDRAM	1	1224 COMPONENT	YES		2000